EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L54	47	L53 and (photoresist with (defect residue contaminat$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:43
L53	1348	L52 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:42
L52	1577	(438/631,633).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 16:42
L51	967	(438/633).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 16:42
L50	13	L47 and (photoresist with (defect residue contaminat$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:42
L46	2628	L45 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:42
L49	5	L47 and (photoresist with contaminat$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:39
L48	107	L47 and polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:39

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		L47 and (photoresist with (defect residue contaminat$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:39
L47	635	L46 and damascene	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:38
L45	3248	(438/692-693).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 16:37
L44	412	L41 NOT (L42 OR L43)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:37
L7	1122	L6 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:37
L43	55	L41 and fuse with trench	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:13
L42	21	L41 and fuse with damascene	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:06
L41	481	L40 and (polysilicon with silicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:06

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L40	72445	fuse.ti. or fuse.ab.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:06
L33	727	L32 and (polysilicon with silicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 16:06
L39	19	("5708291").PN. OR ("5976943"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/02 16:05
L38	2	("5976943").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 15:44
L37	687	L35 NOT L36	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:44
L35	785	L31 or L33	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:43
L36	98	L35 and polysilicon with (damascene trench)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:38
L34	95736	L31 or L32	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:38
L32	95678	resistor.clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:38

L31	230	L30 and (polysilicon with silicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:38
L30	84374	resistor.ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:38
L29	15	polysilicon with damascene and silicid$5 and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:38
L28	212	polysilicon with damascene and silicid$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:37
L24	411	polysilicon with damascene	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:36
L27	43	(polysilicon with (trench damascene)) and (polysilicon with silicidation) and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:34
		(polysilicon with (trench damascene) and (polysilicon with silicidation) and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:33
L26	4	L25 and resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:32

L25	51	L24 and silicidation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:31
L23	411	polysilicon with damascene'	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:31
L22	13062	polysilicon with (trench damascene)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:31
L21	1	("5172211").PN. OR ("6924544"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/02 15:31
L19	275	L16 or L18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:24
L20	24	L15 or L17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:20
L18	162	L5 and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:20
L17	16	L5 and silicidation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:20
L16	177	L14 and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:20

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L15	17	L14 and silicidation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:20
L14	1042	L3 OR L4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:19
L13	430	L9 NOT L10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:19
L8	1005	L7 and silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:19
L12	0	L10 NOT L9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:11
L10	340	L9 and (resistor interconnect metallization)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 15:11
L11	42	("4317700" | "4585515" | "4652334" | "4753709" | "4844776").PN. OR ("4954214").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/02 15:01
L9	770	L8 and polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 14:55
S164	18	S163 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 14:52

L6	1409	L1 or L2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/02 14:52
L5	1503	(257/536).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 14:52
L4	562	(257/538).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 14:52
L3	547	(257/537).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 14:52
L2	807	(438/683).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 14:52
L1	805	(438/682).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/02 14:52
S163	32	S154 and (silicid$5 or salicid$5) with (polysilicon) with (BEOL or back adj end)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:15
S162	14742	S161 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:15

S16 1	19940	S154 and (silicid$5 or salicid$5) with (polysilicon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:15
S15 7	1396	S156 and (silicid$5 or salicid$5) with (trench damascene)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:14
S15 6	3872	S155 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:14
S16 0	36	(silicid$5 or salicid$5) with (trench damascene) with polysilicon with (back adj end or BEOL or interconnect$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:12
S15 9	28	S156 and (silicid$5 or salicid$5) with (trench damascene) with polysilicon with (back adj end or BEOL or interconnect$3 or resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:03
S15 8	392	S156 and (silicid$5 or salicid$5) with (trench damascene) with polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:01
S15 5	5868	S154 and (silicid$5 or salicid$5) same (trench damascene)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:59
S15 1	13524	S150 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:58

S147	1209	S145 and resistor same (silicid$5 or salicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:58
S154	508946	(("257") or ("438") or ("338")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/01 12:57
S152	105	S151 and resistor same (silicid$5 or salicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:57
S144	472858	(("257") or ("438")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/01 12:57
S153	6	S152 and resistor same (trench damascene)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:54
S150	38606	("338").CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/01 12:54
S148	159	S147 and resistor same (trench damascene)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:54
S145	377358	S144 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:54
S149	3	("4728623" | "4782030").PN. OR ("4962365").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/01 12:51

S14 6	4754	S145 and resistor and (silicid$5 or salicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:47
S13 9	40	S138 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:46
S14 3	2	("6815319").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/01 12:45
S14 2	25	("20030089987" | "4024561" | "4347479" | "4399205" | "4516071" | "4659936" | "4871962" | "4978923" | "5485080" | "5497076" | "5552718" | "5834795" | "5928820" | "5963784" | "5989623" | "6030732" | "6057171" | "6066952" | "6072897" | "6087189" | "6150669" | "6171951" | "6204073" | "6207222").PN. OR ("6815319").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/01 12:41
S14 1	5	("4390586" | "5436177" | "6261946" | "6730984" | "6815319").PN. OR ("7122436").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/01 12:40
S14 0	13	("3795977" | "4292384" | "5005101" | "5232865" | "5254217" | "5470780" | "5661503" | "5917286" | "6015728" | "6031250" | "6043516" | "6127217").PN. OR ("6730984").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/01 12:38
S13 8	62	S137 and polysilicon with silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:33
S12 6	389483	S125 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:33

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S13 7	1502	(257/536).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/10/01 12:32
S13 6	30	("3860465" | "4830976" | "5047826" | "5065221").PN. OR ("5352923"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/01 12:31
S13 3	147	S131 and silicid$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/19 18:11
S13 5	5	("5352923" | "5382549" | "5530270" | "5567977").PN. OR ("5856702"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/09/19 18:08
S13 4	30	("3860465" | "4830976" | "5047826" | "5065221").PN. OR ("5352923"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/09/19 18:06
S13 2	123	S131 and silicid$5 with $4silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/19 18:04
S13 1	454	(257/904).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/19 18:03
S12 9	186	S128 and (damascene trough trench opening) with polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/19 18:03
S13 0	2	S128 and (damascene trough) with polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/19 17:58

S12 8	485	S127 and polysilicon near5 silicid$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/19 17:57
S12 7	2137	S126 and polysilicon near5 resistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/19 17:56
S12 5	508093	(("257") or ("438") or ("338")). CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/19 17:56
S12 4	2	("20030122175").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/19 17:48
S12 3	103	S122 NOT S121	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:38
S12 2	126	S110 and (damascene same polysilicon with silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:38
S12 1	23	S110 and (damascene with polysilicon with silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:38
S11 1	1	S110 and (damascene with (resistor passive) with silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:35

S12 0	96	S117 and (polysilicon with interconnect with silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:34
S11 9	0	S117 and (polysilicon with interconnect with BEOL) same silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:34
		S117 and (polysilicon with interconnect with silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:34
S11 8	40	S117 and (resistor with silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:33
S11 7	2270	S116 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:30
S11 6	2502	(438/649,651,655,664).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/17 12:28
S11 0	389453	S109 and @ad<="20031210"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:28
S11 5	10	((damascene trough BEOL) with (resistor passive) with silicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:27

S11 4	3	S110 and ((damascene trough BEOL) with (resistor passive) with silicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:24
S11 3	1	S110 and ((damascene trough) with (resistor passive) with silicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:22
S11 2	1	S110 and (damascene with (resistor passive) with silicid$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:22
S10 9	507855	(("257") or ("438") or ("338")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/17 12:21
S10 8	3	S107 and (damascene with (resistor passive) with silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:21
S10 7	25800	S105 or S106	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/17 12:17
S10 6	16008	(438/381-382,384-385,466,584, 597-599,618,622,642,647-652, 655-657,660,663,682-686).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/17 12:17
S10 5	10832	(257/499,528,536-538,379-380, 382-385,750,754-757,763-764, 768-770).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/17 12:17

EAST SS̄ 10/2/07